



2DB1188P/Q/R

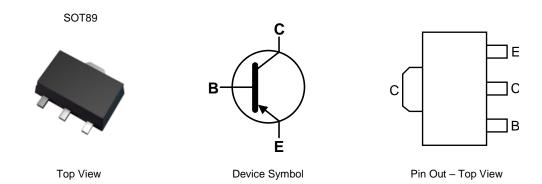
32V PNP MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -32V
- I_C = -2A High Continuous Current
- Low Saturation Voltage V_{CE(sat)} < -800mV @ -2A
- Complementary NPN Type: 2DD1766
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: SOT89
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.052 grams (Approximate)



Ordering Information (Note 4)

Part Number	Status	Compliance	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
2DB1188P-13	Obsolete	Standard	P23P	13	12	2,500
2DB1188Q-13	Active	Standard	P23Q	13	12	2,500
2DB1188Q-13R	Active	Standard	P23Q	13	12	4,000
2DB1188R-13	Active	Standard	P23R	13	12	2,500

Notes:

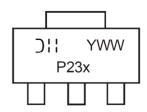
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

 See https://www.diodes.com/quality/lead-free/ for more information about Diodes incorporated s definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Unlead-free.
Unlead-free.<

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



P23x = Product Type Marking Code Where P23P = 2DB1188P P23Q = 2DB1188Q P23R = 2DB1188R \bigcirc YWW = Date Code Marking YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 1 = 2021) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-32	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	Ι _C	-2	A
Peak Pulse Collector Current	I _{CM}	-3	A
Base Current	IB	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

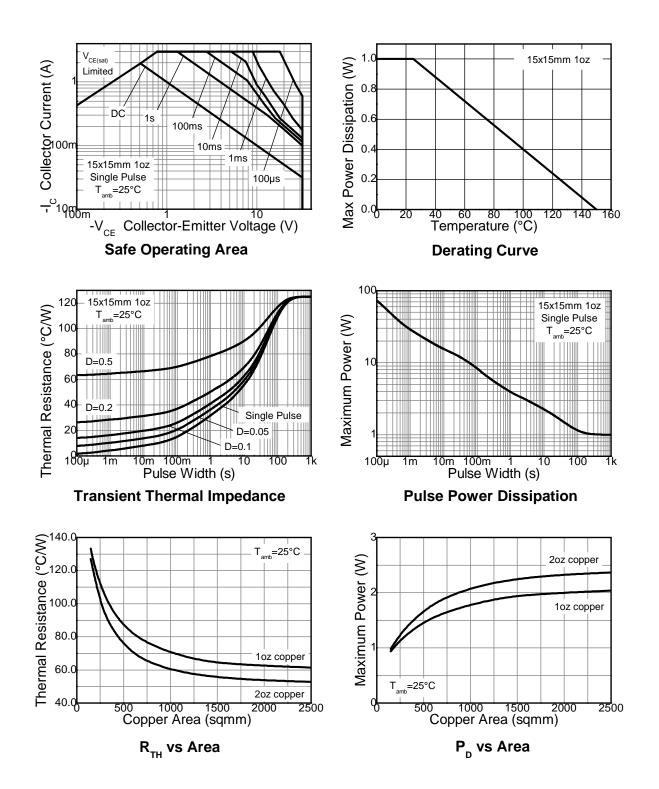
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	Rejl	19	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	۵°

Notes: 5. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Thermal resistance from junction to solder-point (on the exposed collector pad).



Thermal Characteristics and Derating Information

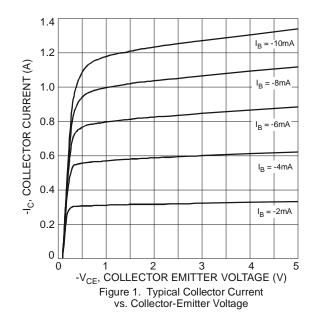


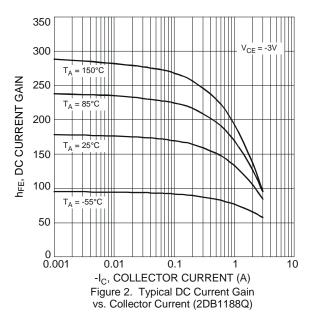


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

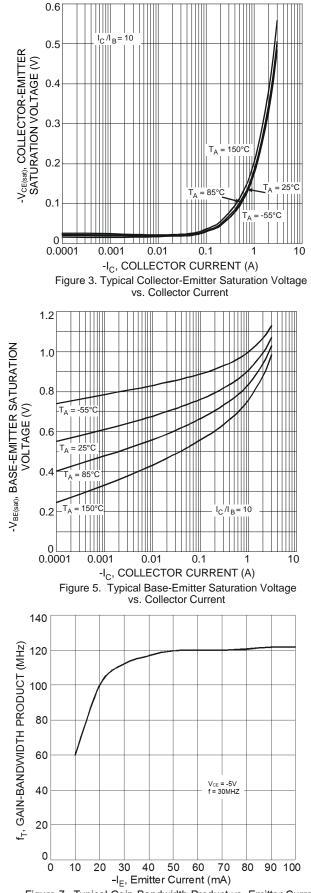
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (N	ote 7)						·
Collector-Base Breakdown Voltage		BV _{CBO}	-40		_	V	I _C = -100μA
Collector-Emitter Breakdown	Voltage	BV _{CEO}	-32		_	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage		BV _{EBO}	-6		_	V	I _E = -100μA
Collector Cutoff Current		I _{CBO}			-100	nA	V _{CB} = -20V
Emitter Cutoff Current		I _{EBO}	_		-100	nA	V _{EB} = - 5V
ON CHARACTERISTICS (No	ote 7)						-
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_	-0.35	-0.8	V	$I_{\rm C} = -2A, I_{\rm B} = -0.2A$
	2DB1188P		82		180		
DC Current Gain	2DB1188Q	h _{FE}	120		270	—	$V_{CE} = -3V, I_{C} = -0.5A$
	2DB1188R		180		390		
SMALL SIGNAL CHARACTE	ERISTICS						
Current Gain-Bandwidth Product		f⊤	_	120	_	MHz	$V_{CE} = -5V, I_C = -0.1A,$ f = 30MHz
Output Capacitance		C _{obo}		20		pF	$V_{CB} = -10V, f = 1MHz$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

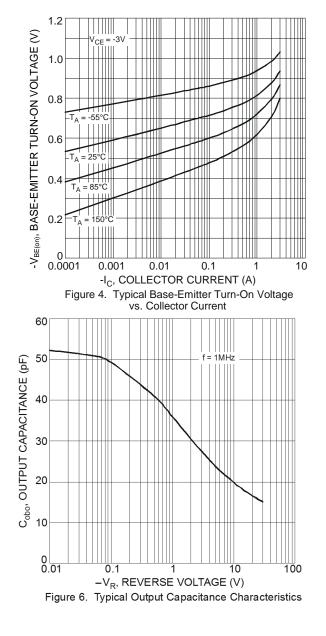








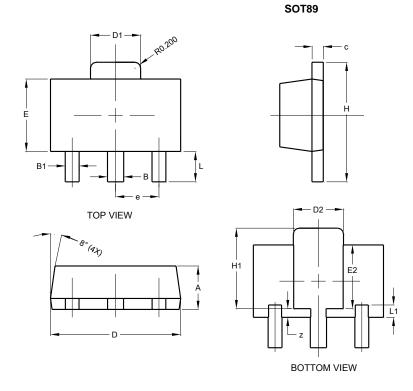






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

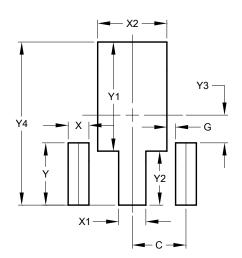


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
E	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	1	-	1.50			
н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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